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## MICROCIRCUIT DATA SHEET

**MDLM119-X REV 2A2**

Original Creation Date: 07/02/01  
Last Update Date: 07/11/01  
Last Major Revision Date:

### HIGH SPEED DUAL COMPARATOR

#### General Description

The LM119 precision high speed dual comparator is fabricated on a single monolithic chip. It is designed to operate over a wide range of supply voltages down to a single 5V logic supply and ground. Furthermore, it has a higher gain and lower input current than other devices. The uncommitted collector of the output stage makes the LM119 compatible with RTL, DTL and TTL as well as capable of driving lamps and relays at currents up to 25mA.

#### Industry Part Number

LM119

#### Prime Die

LM119

#### Controlling Document

SEE FEATURES SECTION

#### NS Part Numbers

LM119E-SMD  
LM119H-QMLV  
LM119H-SMD  
LM119J-QMLV  
LM119J-SMD  
LM119W-QMLV  
LM119W-SMD  
LM119WG-QMLV  
LM119WG-SMD

#### Processing

MIL-STD-883, Method 5004

#### Quality Conformance Inspection

MIL-STD-883, Method 5005

#### Subgrp Description

		Temp ( °C)
1	Static tests at	+25
2	Static tests at	+125
3	Static tests at	-55
4	Dynamic tests at	+25
5	Dynamic tests at	+125
6	Dynamic tests at	-55
7	Functional tests at	+25
8A	Functional tests at	+125
8B	Functional tests at	-55
9	Switching tests at	+25
10	Switching tests at	+125
11	Switching tests at	-55

## **Features**

- Two independent comparators.
- Operates from a single 5V supply.
- Typically 80nS response time at  $\pm 15V$ .
- Minimum fan-out of 2 each side.
- Maximum input current of 1uA over temperature.
- Inputs and outputs can be isolated from system ground.
- High common mode slew rate.

### **- CONTROLLING DOCUMENTS**

LM119E-SMD	86014012A
LM119H-QMLV	5962-9679801VIA
LM119H-SMD	8601401IA
LM119J-QMLV	5962-9679801VCA
LM119J-SMD	8601401CA
LM119W-QMLV	5962-9679801VHA
LM119W-SMD	8601401HA
LM119WG-QMLV	5962-9679801VXA
LM119WG-SMD	8601401X

Although designed primarily for applications requiring operation from digital logic supplies, the LM119 is fully specified for power supplies up to  $\pm 15V$ . It features faster response than the LM111 at the expense of higher power dissipation. However, the high speed, wide operating voltage range and low package count make the LM119 much more versatile than older devices.

**(Absolute Maximum Ratings)**

(Note 1)

Total Supply Voltage	36V
Output to Negative Supply Voltage	36V
Ground to Negative Supply Voltage	25V
Ground to Positive Supply Voltage	18V
Differential Input Voltage	±5V
Input Voltage (Note 3)	±15V
Power Dissipation (Note 2)	500mW
Output Short Circuit Duration	10 seconds
Maximum Junction Temperature	150 °C
Storage Temperature Range	-65 °C to 150 °C
Lead Temperature (Soldering, 10 seconds)	260 °C
Thermal Resistance	
Theta <sub>JA</sub>	
E Package (Still Air)	89 °C/W
E Package (500LF/Min Air flow)	63 °C/W
H Package (Still Air)	162 °C/W
H Package (500LF/Min Air flow)	88 °C/W
J Package (Still Air)	94 °C/W
J Package (500LF/Min Air flow)	52 °C/W
W Package (Still Air)	215 °C/W
W Package (500LF/Min Air flow)	132 °C/W
WG Package (Still Air)	215 °C/W
WG Package (500LF/Min Air flow)	132 °C/W
Theta <sub>JC</sub>	
E Package	5 °C/W
H Package	31 °C/W
J Package	11 °C/W
W Package	13 °C/W
WG Package	13 °C/W
Package Weight	
E Package	TBD
H Package	TBD
J Package	TBD
W Package	TBD
WG Package	225mg
ESD Tolerance (Note 4)	800V

- Note 1: Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is functional, but do not guarantee specific performance limits. For guaranteed specifications and test conditions, see the Electrical Characteristics. The guaranteed specifications apply only for the test conditions listed. Some performance characteristics may degrade when the device is not operated under the listed test conditions.
- Note 2: The maximum power dissipation must be derated at elevated temperatures and is dictated by  $T_{jmax}$  (maximum junction temperature),  $\Theta_{JA}$  (package junction to ambient thermal resistance), and  $T_A$  (ambient temperature). The maximum allowable power dissipation at any temperature is  $P_{dmax} = (T_{jmax} - T_A)/\Theta_{JA}$  or the number given in the Absolute Maximum Ratings, whichever is lower.
- Note 3: For supply voltages less than  $\pm 15V$  the absolute maximum input voltage is equal to the supply voltage.
- Note 4: Human body model, 1.5K Ohm in series with 100pF.

## **Recommended Operating Conditions**

Operating Temperature Range

-55 C  $\leq$   $T_A$   $\leq$  125 C

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## Electrical Characteristics

### DC PARAMETERS:

(The following conditions apply to all the following parameters, unless otherwise specified.)  
DC: Vcm = 0V

SYMBOL	PARAMETER	CONDITIONS	NOTES	PIN-NAME	MIN	MAX	UNIT	SUB-GROUPS
Icc+	Positive Supply Current	$\pm V_{CC} = \pm 15V$			11	mA	1	
					11.5	mA	2, 3	
Icc-	Negative Supply Current	$\pm V_{CC} = \pm 15V$			-4.2		mA	1
					-4.5		mA	2
					-6		mA	3
Ileak	Output Leakage Current	$+V_{CC} = 15V, -V_{CC} = -1V, V_{GND} = 0V, V_{OUT} = 35V$	1		1.8	uA	1	
			1		10	uA	2, 3	
Iib	Input Bias Current	$\pm V_{CC} = \pm 15V$			0.475	uA	1	
					0.95	uA	2, 3	
		$V_{CC} = 5V$	2		0.475	uA	1	
			2		.95	uA	2, 3	
Vio	Input Offset Voltage	$V_{CC} = 5V, V_{CM} = 1V, R_S \leq 5K$	2		-3.8	3.8	mV	1
			2		-6.8	6.8	mV	2, 3
		$V_{CC} = 5V, V_{CM} = 3V, R_S \leq 5K$	2		-3.8	3.8	mV	1
			2		-6.8	6.8	mV	2, 3
		$\pm V_{CC} = \pm 15V, V_{CM} = 12V, R_S \leq 5K$			-3.8	3.8	mV	1
					-6.8	6.8	mV	2, 3
		$\pm V_{CC} = \pm 15V, V_{CM} = -12V, R_S \leq 5K$			-3.8	3.8	mV	1
					-6.8	6.8	mV	2, 3
Iio	Input Offset Current	$V_{CC} = 5V, V_{CM} = 1V$	2		-75	75	nA	1
			2		-100	100	nA	2, 3
		$V_{CC} = 5V, V_{CM} = 3V$	2		-75	75	nA	1
			2		-100	100	nA	2, 3
		$\pm V_{CC} = \pm 15V, V_{CM} = 12V$			-75	75	nA	1
					-100	100	nA	2, 3
		$\pm V_{CC} = \pm 15V, V_{CM} = -12V$			-75	75	nA	1
					-100	100	nA	2, 3
Vi	Input Voltage Range	$V_{CC} = 5V$	2, 3		1	3	V	1, 2, 3
		$V_{CC} = \pm 15V$	3		-12	12	V	1, 2, 3

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## Electrical Characteristics

### DC PARAMETERS: (Continued)

(The following conditions apply to all the following parameters, unless otherwise specified.)  
 DC:  $V_{cm} = 0V$

SYMBOL	PARAMETER	CONDITIONS	NOTES	PIN-NAME	MIN	MAX	UNIT	SUB-GROUPS
Vsat	Output Saturation Voltage	Vcc = $\pm 15V$ , $I_{out} = 25mA$ , $V_{in} \leq -5mV$	1			1.5	V	1, 2, 3
		+Vcc = 3.5V, -Vcc = -1V, $V_{in} \leq -6mV$ , $I_{sink} \leq 3.2mA$				0.4	V	1, 2
						0.6	V	3
Av	Voltage Gain	$\pm V_{cc} = \pm 15V$ , Delta $V_{out} = 12V$	4		10.5		K	4
			4		10		K	5, 6
		$V_{cc} = 5V$ , Delta $V_{out} = 4.5V$	2, 4		8		K	4
			2, 4		5		K	5
			2, 4		5.8		K	6
CMRR	Common Mode Rejection Ratio	$\pm V_{cc} = \pm 15V$ , $V_{cm} = \pm 12V$			80		dB	4

### DC PARAMETERS: DRIFT VALUES

(The following conditions apply to all the following parameters, unless otherwise specified.)  
 DC:  $V_{cm} = 0V$ . Delta calculations performed on JAN S and QMLV devices at group B, subgroup 5 ONLY.

Icc+	Positive Supply Current	$\pm V_{cc} = \pm 15V$			-1	1	mA	1
Icc-	Negative Supply Current	$\pm V_{cc} = \pm 15V$			-0.5	0.5	mA	1
Vio	Input Offset Voltage	$V_{cc} = 5V$ , $V_{cm} = 1V$ , $R_s \leq 5K$			-0.4	0.4	mV	1

Note 1:  $V_{in} \geq 8mV$  at extremes for  $I_{leak}$  and  $V_{in} \leq -8mV$  at extremes for Vsat ( $V_{in}$  to exceed  $V_{os}$ ).

Note 2: 5 Volt differential across +Vcc and -Vcc.

Note 3: Parameter guaranteed by Vio and Iio tests.

Note 4: K = V/mV.

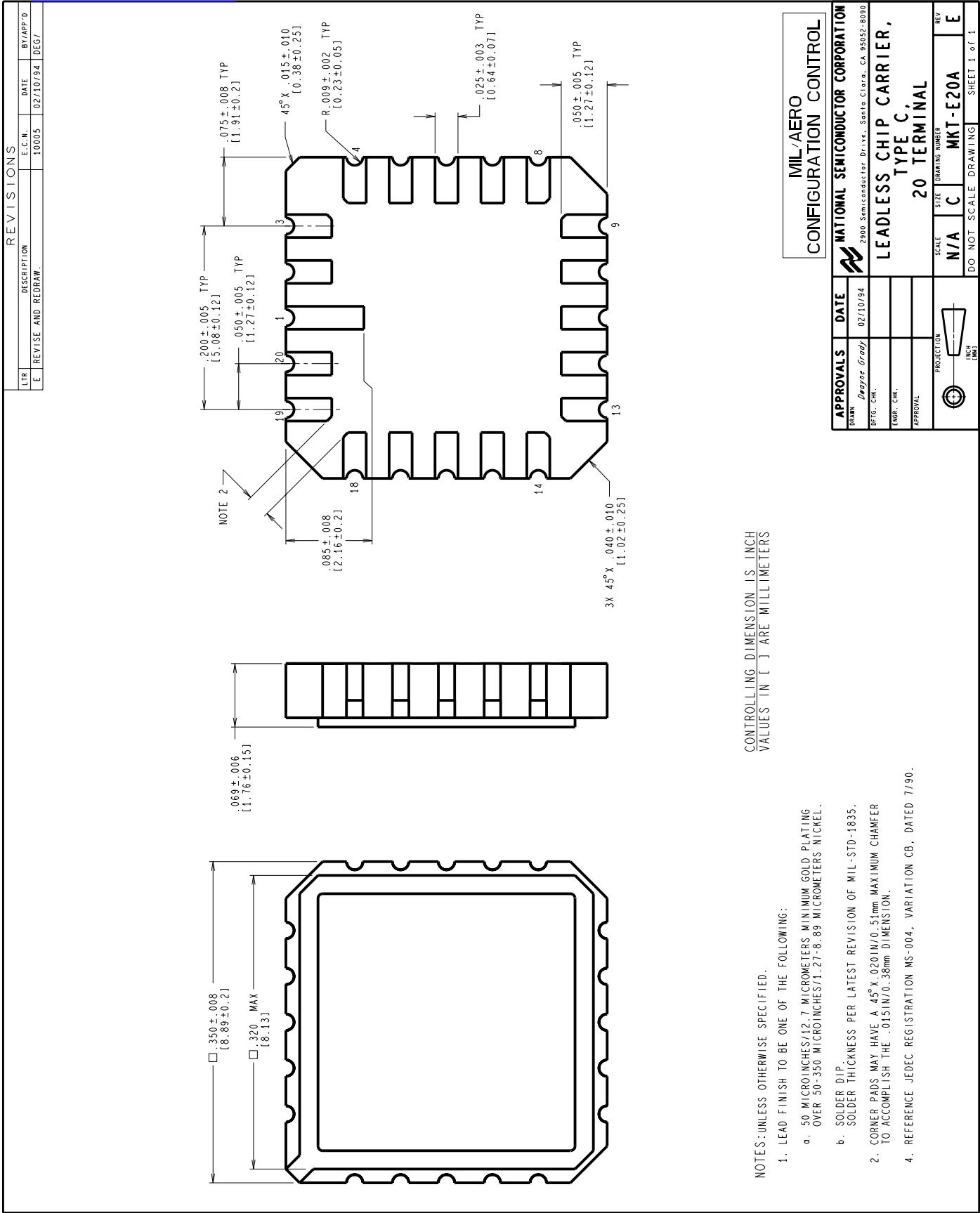
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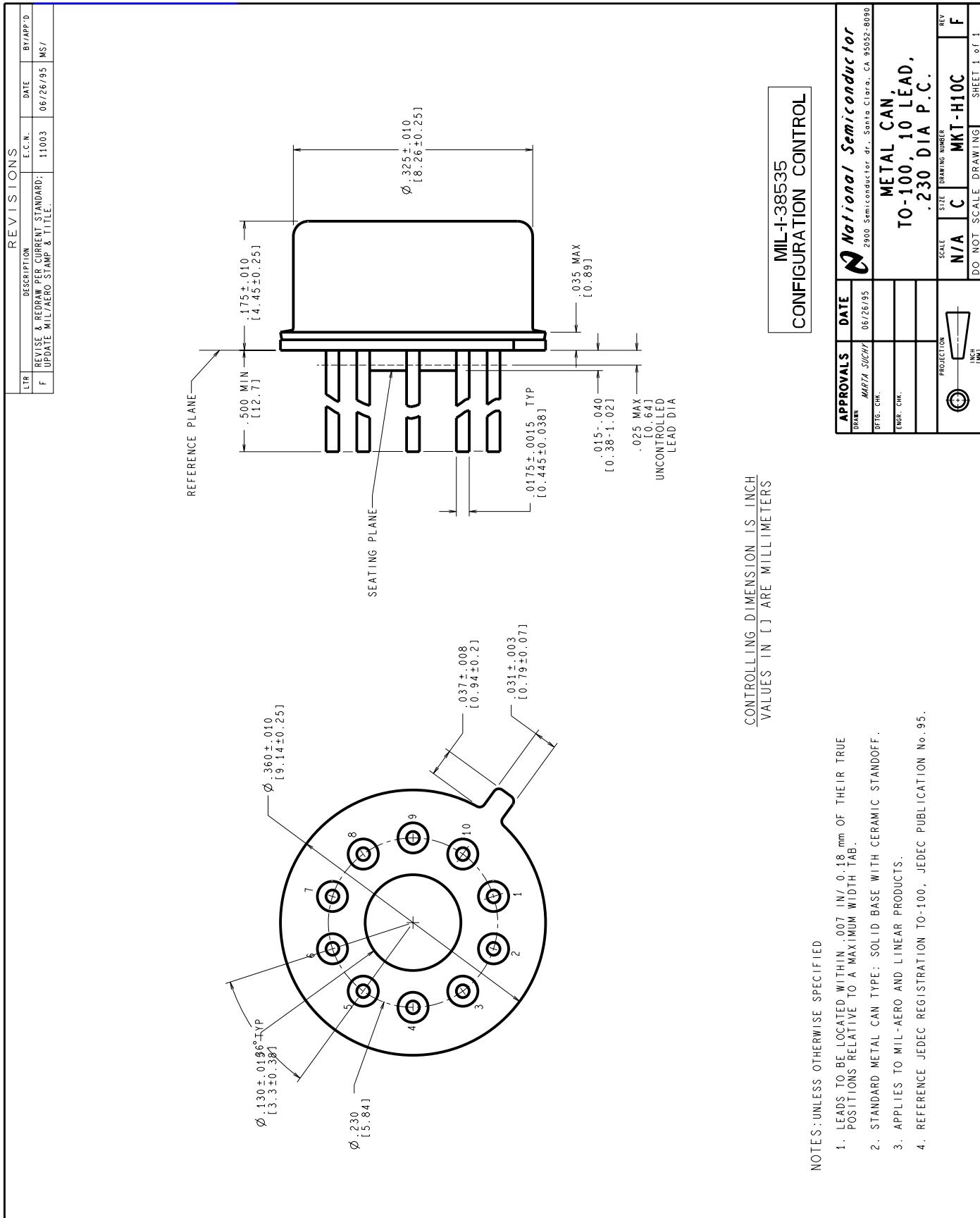
**Graphics and Diagrams**

GRAPHICS#	DESCRIPTION
06142HRA3	LCC (E), TYPE C, 20 TERMINAL (B/I CKT)
08906HRB3	METAL CAN (H), 10 LEAD (B/I CKT)
09078HRB3	CERPACK (W), 10 LEAD (B/I CKT)
09641HRA2	CERDIP (J), 14 LEAD (B/I CKT)
E20ARE	LCC (E), TYPE C, 20 TERMINAL(P/P DWG)
H10CRF	METAL CAN (H), TO-100, 10LD, .230 DIA PC (P/P DWG)
J14ARH	CERDIP (J), 14 LEAD (P/P DWG)
P000182A	CERDIP (J), 14 LEAD (PINOUT)
P000196A	LCC (E), 20 LEAD (PINOUT)
P000197A	METAL CAN (H), TO-100, 10 LD, .230 DIA PC (PINOUT)
P000198A	CERPACK (W), 10 LEAD (PINOUT)
P000237A	CERAMIC SOIC (WG), 10 LEAD (PINOUT)
W10ARG	CERPACK (W), 10 LEAD (P/P DWG)
WG10ARC	CERAMIC SOIC (WG), 10 LEAD (P/P DWG)

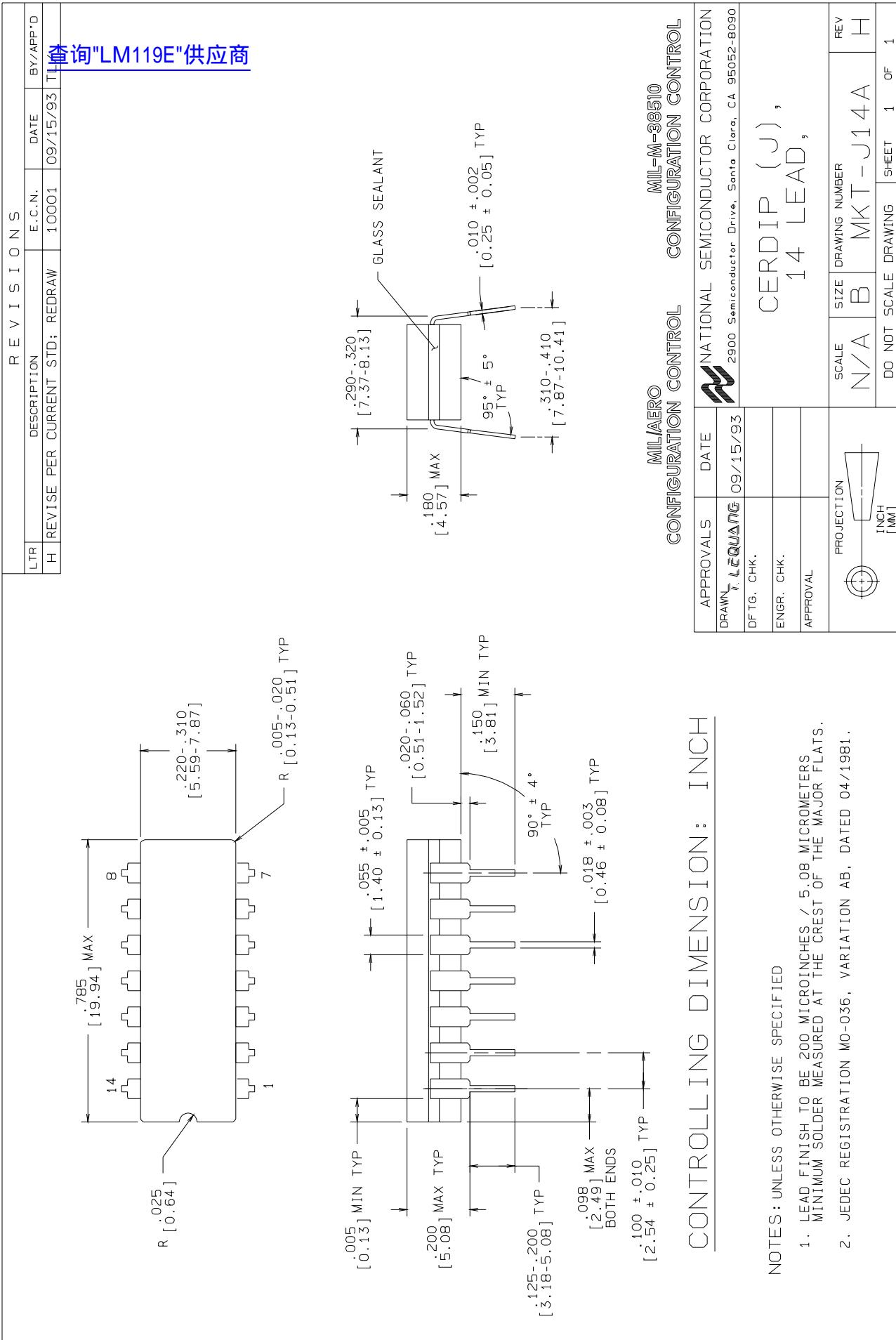
See attached graphics following this page.

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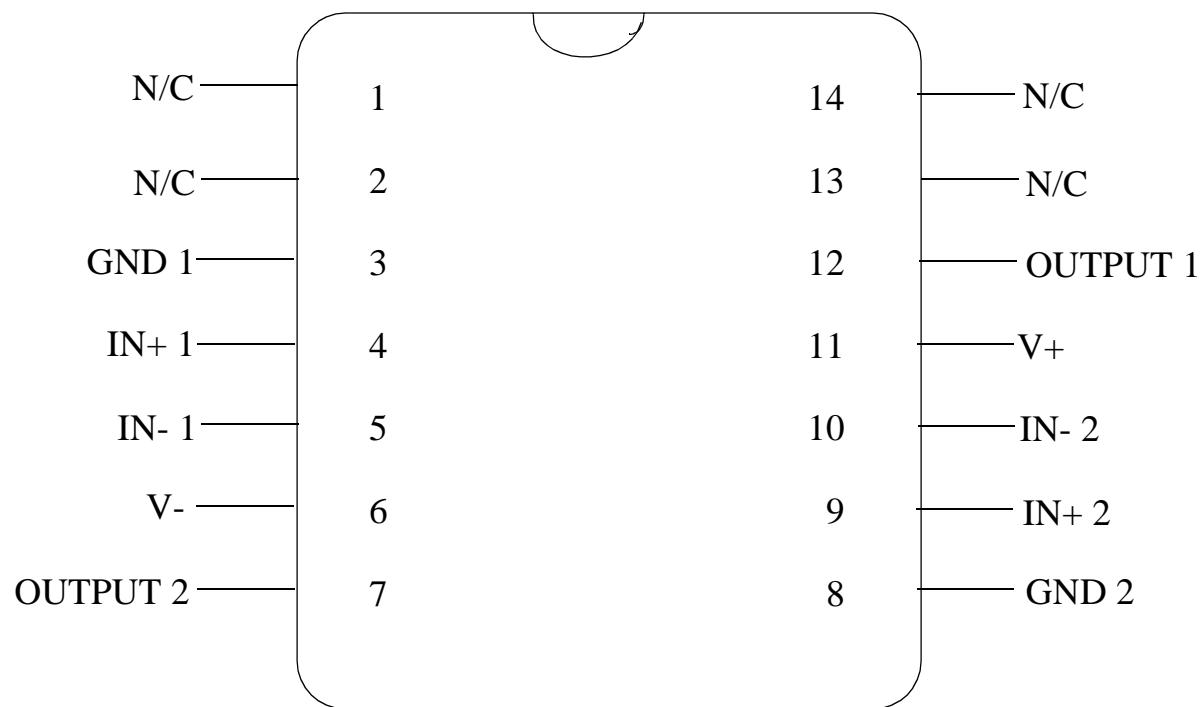




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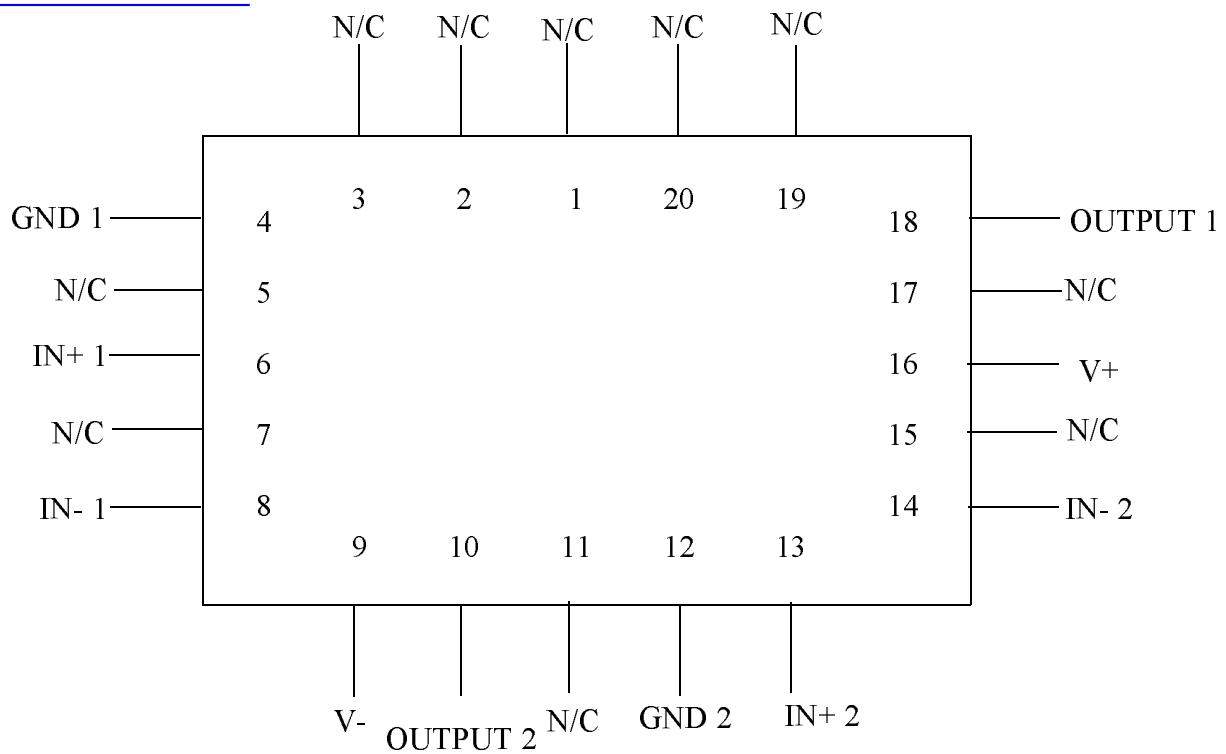


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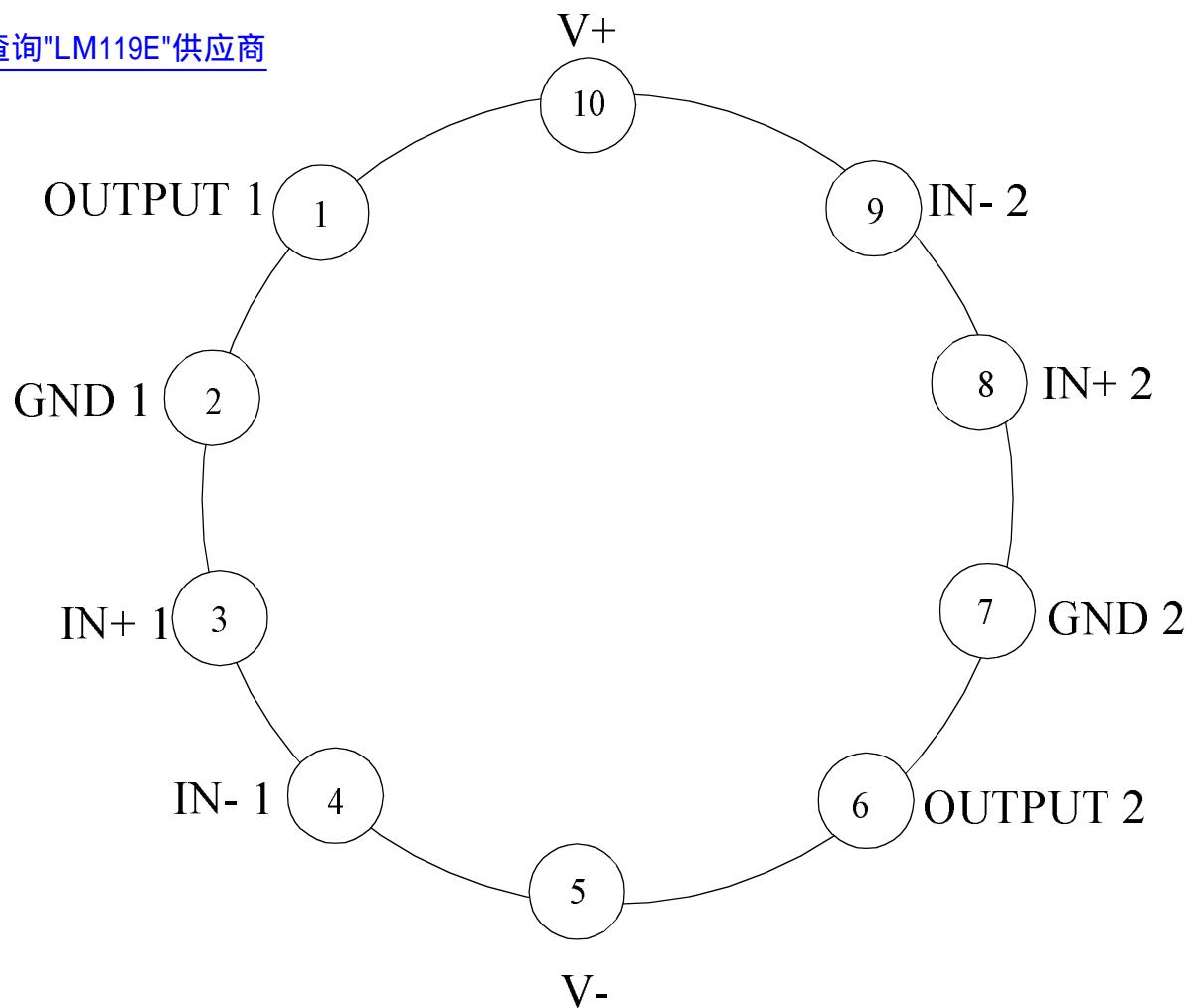
**LM119J**  
**14 - LEAD DIP**  
**CONNECTION DIAGRAM**  
**TOP VIEW**  
**P000182A**

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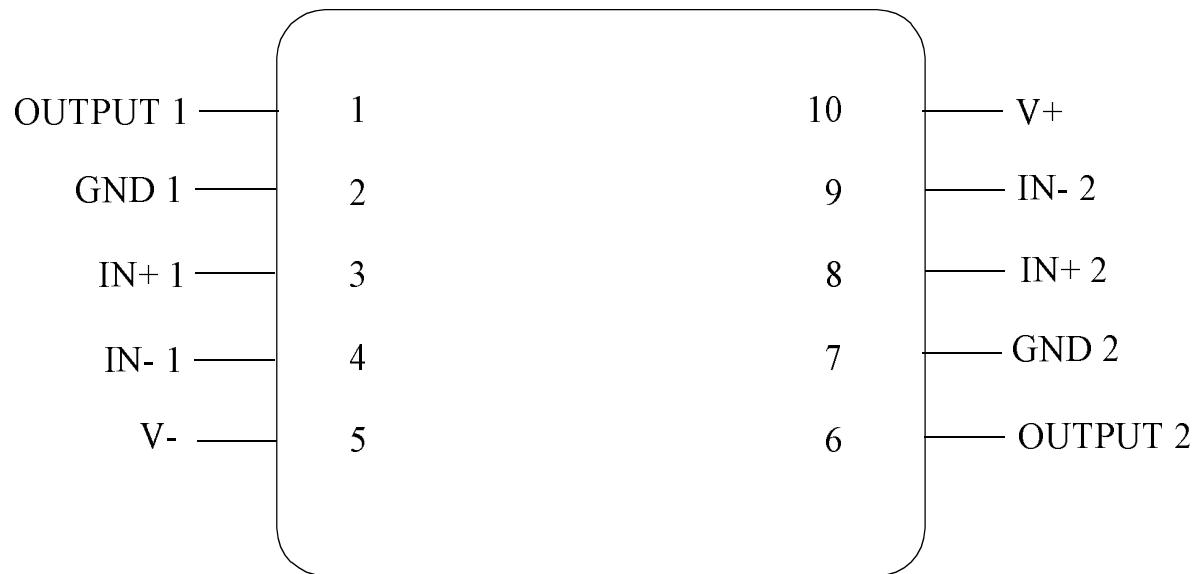
LM119E  
20 - LEAD LCC  
CONNECTION DIAGRAM  
TOP VIEW  
P000196A

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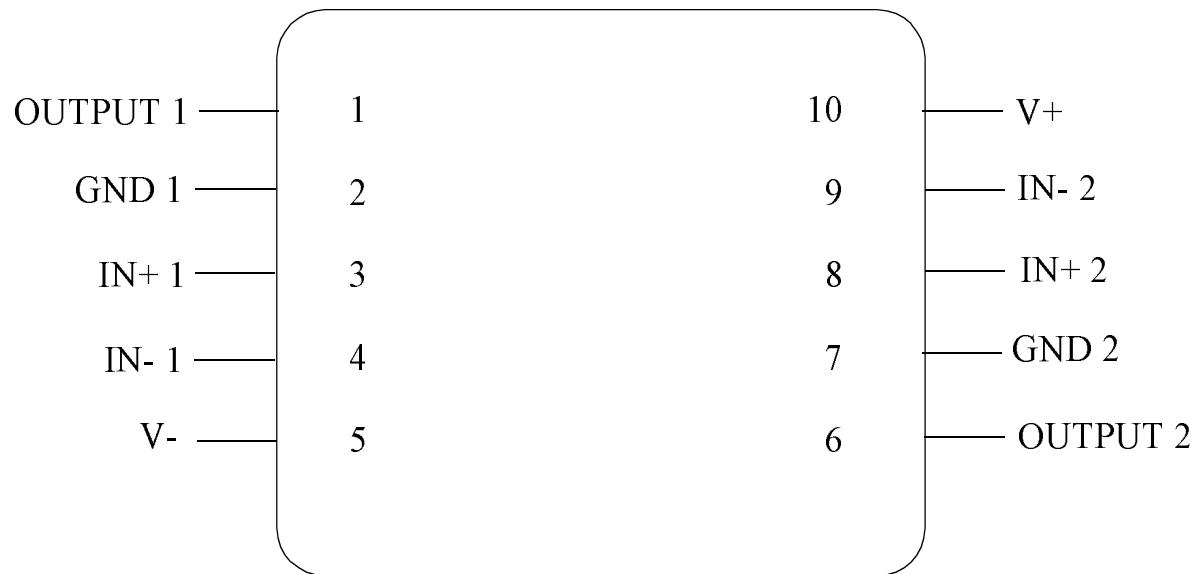
LM119H  
10 - PIN METAL CAN  
CONNECTION DIAGRAM  
TOP VIEW  
P000197A

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**LM119W**  
**10 - LEAD CERPACK**  
**CONNECTION DIAGRAM**  
**TOP VIEW**  
**P000198A**

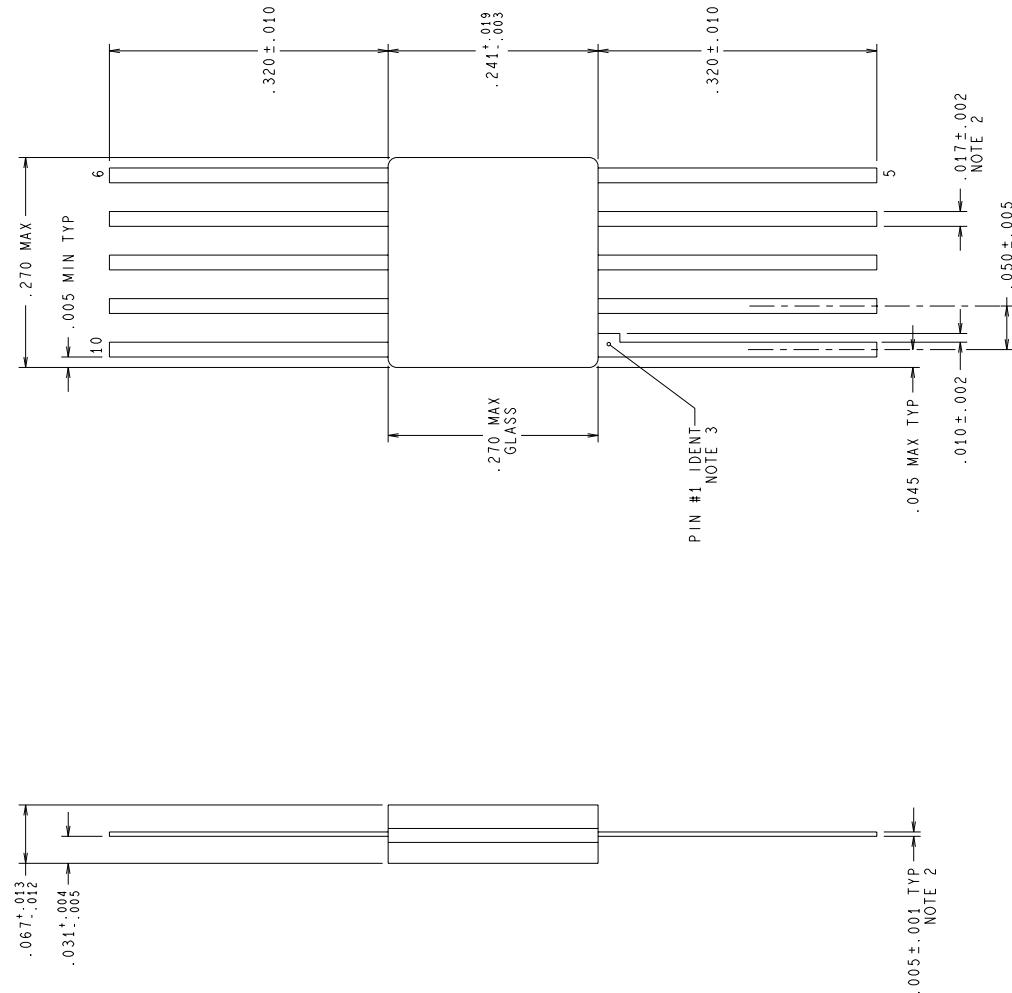
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LM119WG  
10 - LEAD CERAMIC SOIC  
CONNECTION DIAGRAM  
TOP VIEW  
P000237A

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REVISI ONS					
LTR	DESCRIPTION	E.C.N.	DATE	BY APP	
F	REVISE AND REDRAW PER NEW STANDARD	10510	07/28/94	DEG/AEP	
G	.017±.002 WAS .017±.020.	10554	10/21/94	DEG	

MIL/AERO CONFIGURATION CONTROL	
MIL-M-38510 CONFIGURATION CONTROL	

**NOTES: UNLESS OTHERWISE SPECIFIED.**

1. LEAD FINISH: SOLDER DIPPED WITH S60 OR Sn63 SOLDER CONFORMING TO MIL-M-38510 TO A MINIMUM THICKNESS OF 200 MICROINCHES. SOLDER MAY BE APPLIED OVER LEAD BASIS METAL OR Sn PLATE.
2. MAXIMUM LIMIT MAY BE INCREASED BY .003 INCHES AFTER LEAD FINISH APPLIED.
3. LEAD 1 IDENTIFICATION SHALL BE:
  - a) A NOTCH OR OTHER MARK WITHIN THIS AREA
  - b) A TAB ON LEAD 1, EITHER SIDE
4. REFERENCE JEDEC REGISTRATION MO-003, VARIATION AG, DATED 06/01/76.

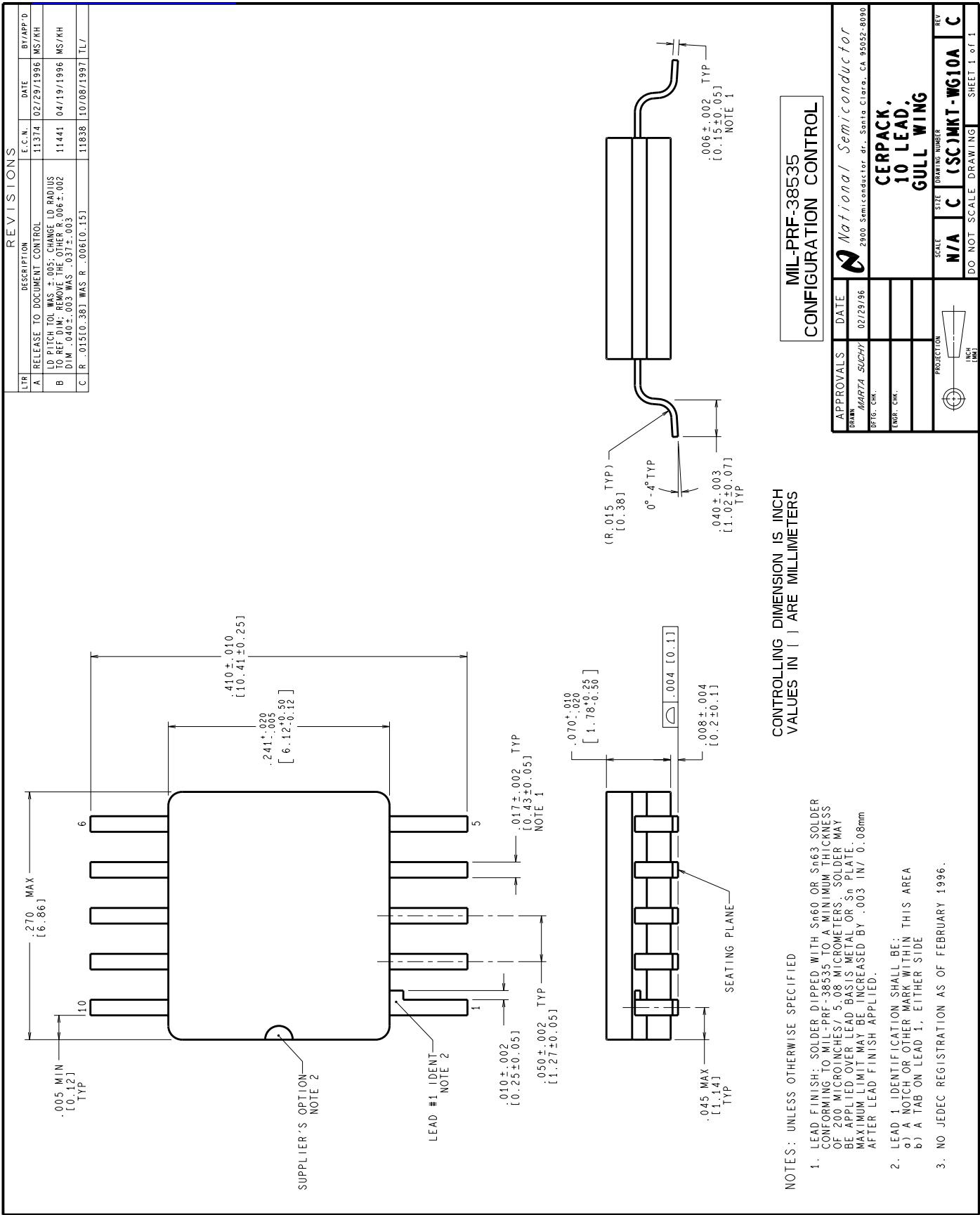
  

NATIONA L SEMICONDUCTOR	
APPROVALS	DATE
DRAWN D.E. Gandy	07/28/94
DTG. CHK. Engg. CHK.	
CERPACK, 10 LEAD	

PROJECTION	SCALE	SIZE	DRAWING NUMBER
1.000 [MM]	N/A	C	MKT-W10A
HEV			
DO NOT SCALE DRAWING		SHEET 1 OF 1	

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**MDLM119-X REV 2A2**

**MICROCIRCUIT DATA SHEET**

**Revision History**

<b>Rev</b>	<b>ECN #</b>	<b>Rel Date</b>	<b>Originator</b>	<b>Changes</b>
0B0	M0001371	02/25/98	Barbara Lopez	Added Power Dissipation - Note 2 in Absolute section. Renumbered all other notes. Archive MDS - MDLM119-X Rev. 0A0. Release MDS - MDLM119-X Rev. 0B0.
0C1	M0002726	12/06/99	Barbara Lopez	Update MDS: MDLM119-X Rev. 0B0 to MDLM119-X Rev. 0C1. Added WG package to MDS. Added MKT outline, Burn-In CKT and Pinouts.
1C1	M0003596	12/06/99	Rose Malone	Archive MDLM119-X, Rev. 0C1. MDS replaced by MDLM119-X-RH, Rev. 0A0. MDS is being archived as Rev. 1C1.
2A2	M0003821	07/11/01	Rose Malone	De-Archived MDS: MDLM119-X, Re-Instate back into system at Rev. 2A2. Removed Rad Devices, MDLM119-X references Non Rad Devices ONLY. MDLM119-X, Rev. 2A2 replaces MDLM119-X-RH